SN54HCT00, SN74HCT00 QUADRUPLE 2-INPUT POSITIVE-NAND GATES

SCLS062B - NOVEMBER 1988 - REVISED MAY 1997

- Inputs Are TTL-Voltage Compatible
- Package Options Include Plastic Small-Outline (D), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

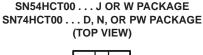
description

These devices contain four independent 2-input NAND gates. They perform the Boolean function $Y = \overline{A} \cdot \overline{B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The SN54HCT00 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74HCT00 is characterized for operation from -40° C to 85° C.

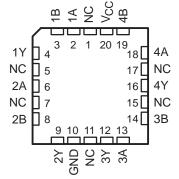
FUNCTION TABLE (each gate)							
INP	UTS	OUTPUT					
Α	В	Y					
Н	Н	L					
L	Х	н					
Х	L	н					

logic symbol[†]

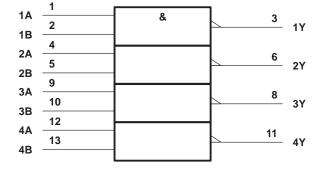


		\Box		L
1A [-	14	JVcc
1B [] V _{CC}] 4B
1Y [3		12] 4A
2A [4		11] 4Y
			10] 3B
2Y [6		9] 3A
GND [7		8] 3Y

SN54HCT00 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, N, PW, and W packages.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range[†]

$\begin{array}{llllllllllllllllllllllllllllllllllll$	±20 mA ±20 mA ±25 mA ±50 mA 27°C/W 78°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

			SN	154HCT00	SN74HCT00			UNIT
			MIN	NOM MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage		4.5	5 💉 5.5	4.5	5	5.5	V
VIH	High-level input voltage	V_{CC} = 4.5 V to 5.5 V	2	W	2			V
VIL	Low-level input voltage	V_{CC} = 4.5 V to 5.5 V	0	0.8	0		0.8	V
VI	Input voltage		0	Vcc	0		VCC	V
VO	Output voltage		0	S Vcc	0		VCC	V
tt	Input transition (rise and fall) time		00	500	0		500	ns
T _{Az}	Operating free-air temperature		-55	125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		Vee	T _A = 25°C			SN54HCT00		SN74HCT00		UNIT
PARAMETER	TEST CO		Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
VOH	VI = VIH or VIL	I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
VOH		I _{OH} = -4 mA	4.5 V	3.98	4.3		3.7		3.84		v
Ve	$\lambda = \lambda = 0$	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL	$V_{I} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 4 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	v
li	$V_{I} = V_{CC} \text{ or } 0$		5.5 V		±0.1	±100	4	±1000		±1000	nA
ICC	$V_I = V_{CC} \text{ or } 0,$	IO = 0	5.5 V			2	(C)	40		20	μA
∆ICC‡	One input at 0.5 V o Other inputs at 0 or		5.5 V		1.4	2.4	ydog	3		2.9	mA
Ci			4.5 V to 5.5 V		3	10	1	10		10	pF

[‡]This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

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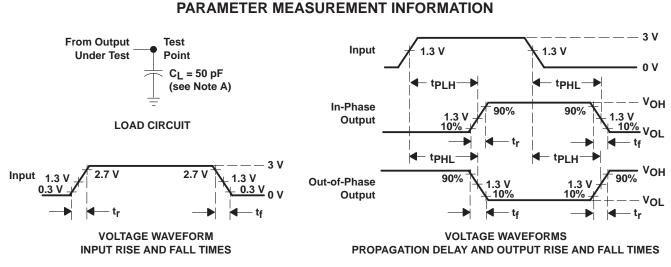
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switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	ADAMETED FROM TO		Vee	Τį	λ = 25°C	;	SN54HCT00	SN74HCT00	UNIT
PARAMETER	(INPUT)	(OUTPUT)	vcc	MIN	TYP	MAX	MIN MAX	MIN MAX	UNIT
. .	A or D	Y	4.5 V		11	20	30	25	
^t pd	A or B		ſ	5.5 V		10	18	27	22
		V	4.5 V		9	15	22	19	
ut l		T	5.5 V		8	14	20	17	ns

operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per gate	No load	20	pF



- NOTES: A. CL includes probe and test-fixture capacitance.
 - B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns. t_f = 6 ns.
 - C. The outputs are measured one at a time with one input transition per measurement.
 - D. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



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